

1-Line Bi-directional ESD Protection Diode

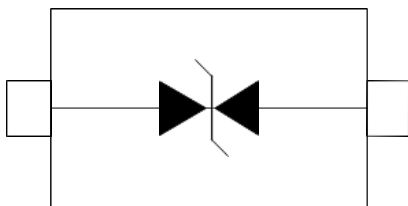
Description

These surge protection diodes are designed for applications requiring transient over voltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

Features

- Bi-directional ESD protection of one line
- Reverse stand-off voltage: 48.0V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 9.0A (8/20 μs)
- RoHS Compliant

Schematic and Pin Configuration



SOD-323 (Top View)

Circuit Schematic

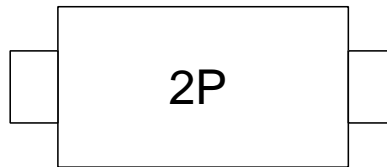
Mechanical Characteristics

- SOD-323 Small Outline Plastic Package
- Level 1 moisture sensitivity per J-STD-020
- Case Material: “Green” Molding Compound
- Lead Finish: Matte Tin
- We declare that the material of product compliance With RoHS requirements and Halogen Free

Applications

- Cell Phone
- Audio equipment
- Portable devices
- Digital cameras
- Power supplies

Marking Information

**2P** = Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PSD48C	3000/Tape & Reel	7 inch

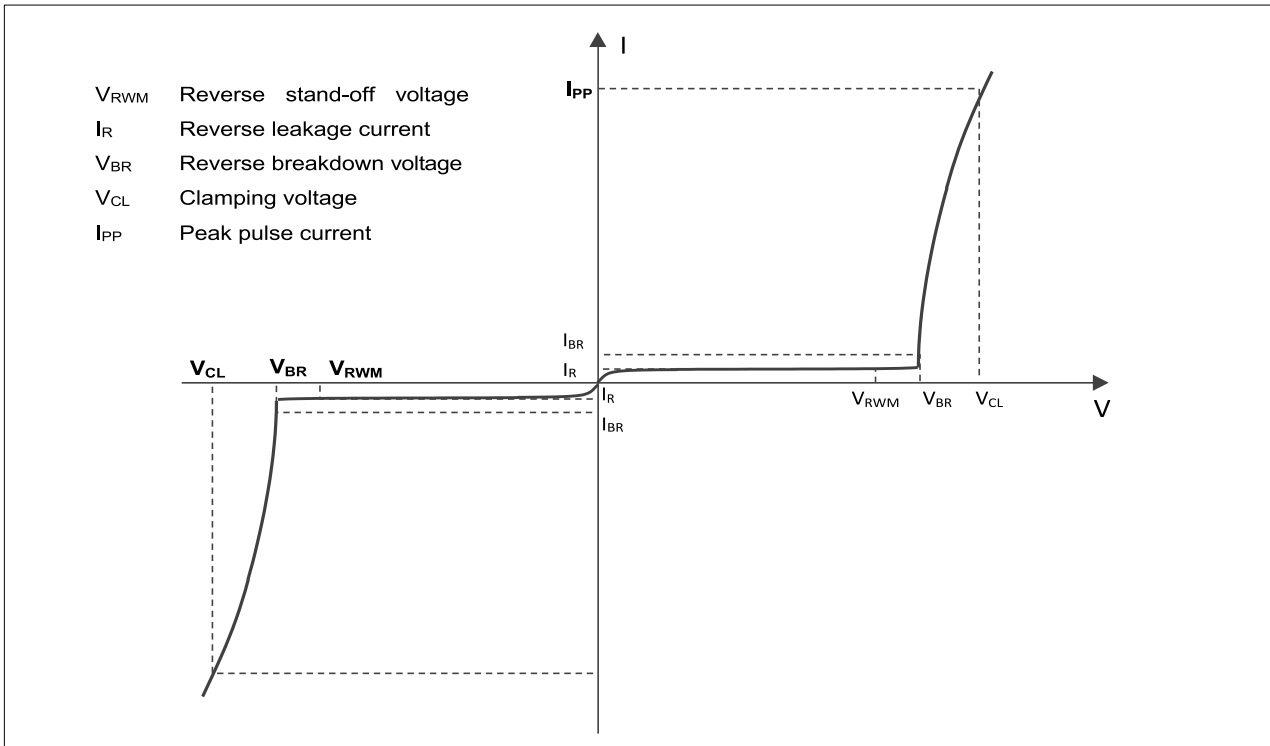
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P _{PK}	760	W
Peak Pulse Current (8/20μs)	I _{PP}	9	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	kV
Maximum lead temperature for soldering during 10s	T _L	260	°C
Operating Temperature Range	T _{OP}	-40 to +125	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

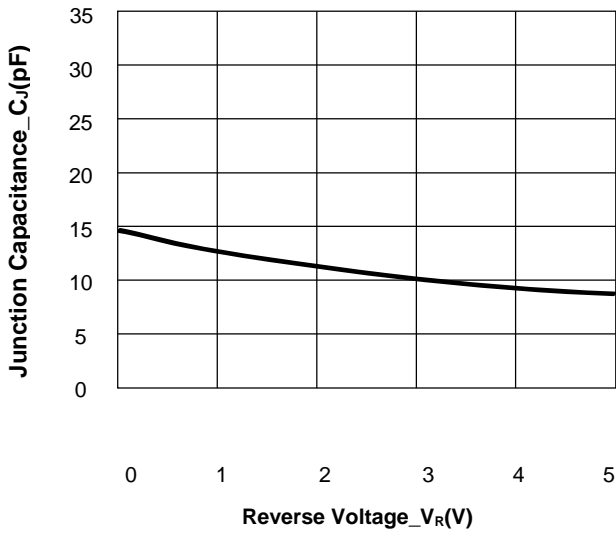
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			48	V	
Reverse Breakdown Voltage	V _{BR}	52		65	V	I _T = 1mA
Reverse Leakage Current	I _R			100	nA	V _{RWM} = 48V
Clamping Voltage	V _C		64	72	V	I _{PP} = 3A (8/20μs pulse)
Clamping Voltage	V _C		80	84	V	I _{PP} = 9A (8/20μs pulse)
Junction Capacitance	C _J		15	20	pF	V _R = 0V, f = 1MHz

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

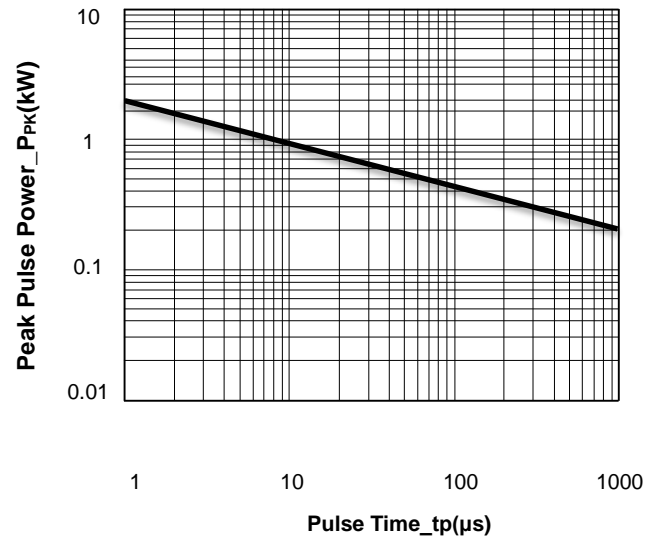


Definitions of electrical characteristics

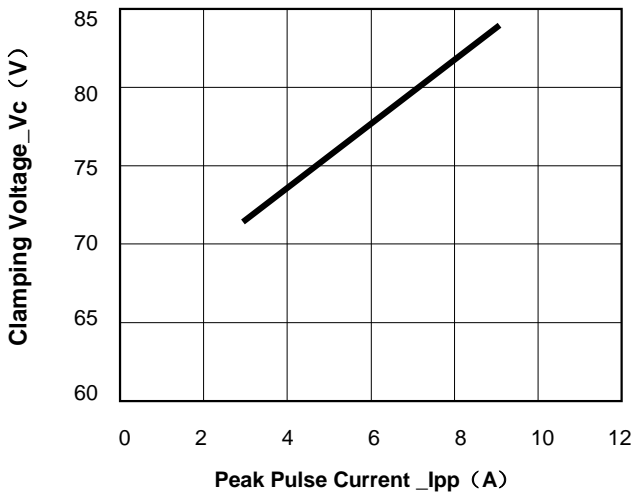
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



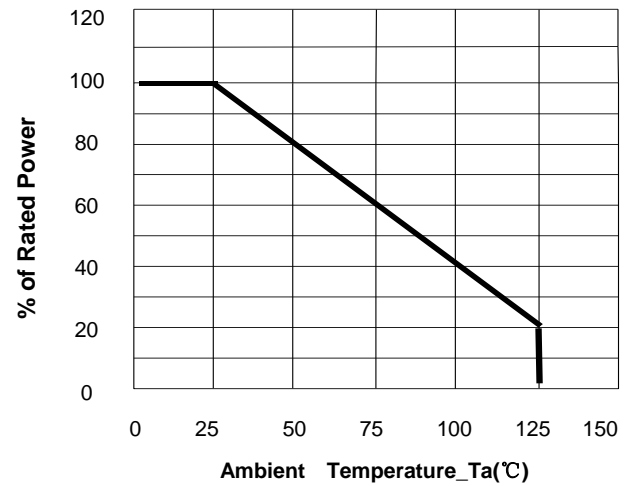
Junction Capacitance vs. Reverse Voltage



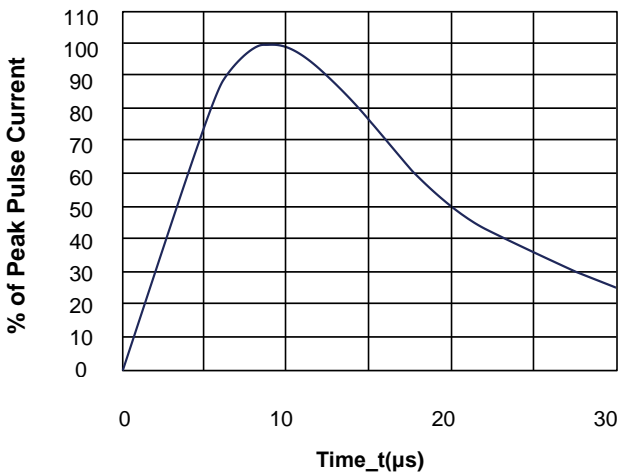
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

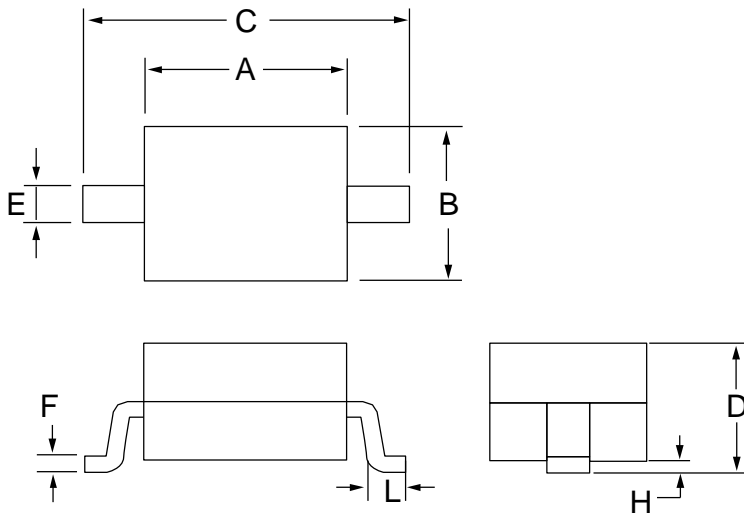


Power Derating Curve



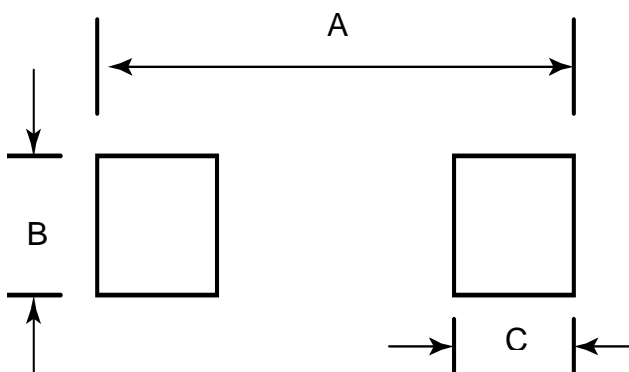
8/20μs Pulse Waveform

SOD-323 Package Outline Drawing



SYM	DIMENSIONS				
	MILLIMETERS			INCHES	
	MIN	NOM	MAX	MIN	MAX
A	1.50	1.65	1.80	0.060	0.071
B	1.20	1.30	1.40	0.045	0.054
C	2.30	2.50	2.70	0.090	0.107
D	-		1.10	-	0.043
E	0.30		0.40	0.012	0.016
F	0.10		0.25	0.004	0.010
L	0.20		0.40	0.008	0.016
H	-		0.10	-	0.004

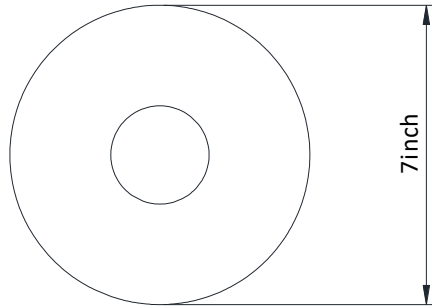
Suggested Land Pattern



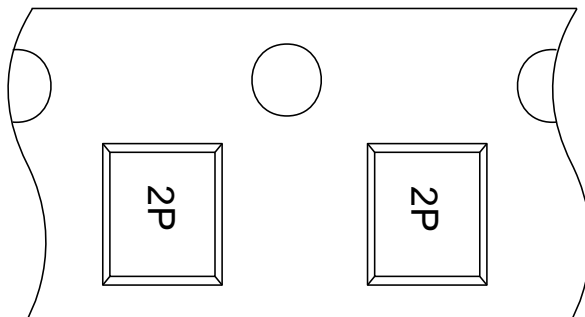
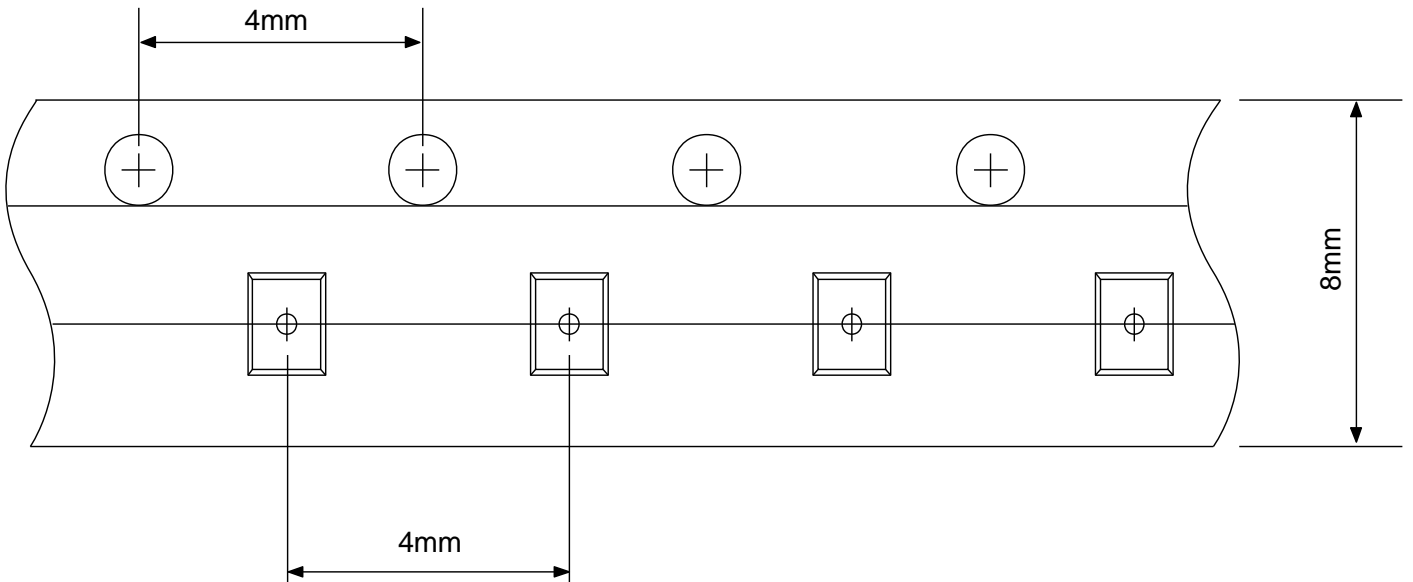
SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions




User Direction of Feed

IMPORTANT NOTICE

The information given in this document is believed to be accurate and reliable but shall in no event be regarded as a guarantee of conditions or characteristics. PN-Silicon assumes no responsibility for any errors in this document, or for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of PN-Silicon.

The product listed in this document are designed to be used with ordinary electronic equipment or devices and are not authorized to used with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, automotive and other safety device.)

The  logo is a registered trademark of PN-Silicon co., ltd which reserves the right to make changes to the product or this document at any time without notice. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. PN-Silicon makes no warranty, representation or guarantee, express or implied, regarding the suitability of its products for any particular purpose. All rights reserved.